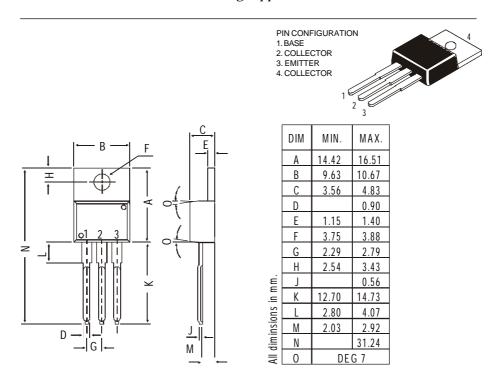




### **TO-220 Plastic Package**

#### BD533, BD535, BD537 BD534, BD536, BD538

# BD533, 535, 537NPN PLASTIC POWER TRANSISTORSBD534, 536, 538PNP PLASTIC POWER TRANSISTORSMedium Power Linear and Switching Applications



ABSOLUTE MAXIMUM RATINGS			533 534	535 536	537 538	
Collector-base voltage (open emitter)	V <sub>CBO</sub>	max.	45	60	80	V
Collector-emitter voltage (open base)	$V_{CEO}$	max.	45	60	80	V
Collector and emitter current	$I_{C}, I_{E}$	max.		8.0		Α
Total power dissipation up to $T_C = 25^{\circ}C$	P <sub>tot</sub>	max.		50		W
Junction temperature	$T_i$	max.		150		$^{\circ}C$
Collector-emitter saturation voltage	5					
$I_C = 2 A; I_B = 0.2 A$	V <sub>CEsat</sub>	max.		0.8		V
D.C. current gain						
$I_C = 10 \text{ mA}; V_{CE} = 5 V$	h <sub>FE</sub>	min.	20	20	15	
<b>RATINGS</b> (at $T_A=25^{\circ}C$ unless otherwise specified)				535 536	537 538	
Collector-base voltage (open emitter)	V <sub>CBO</sub>	max.	45	60	80	V
Collector-emitter voltage (open base)	$V_{CEO}$	max.	45	60	80	V
Collector-emitter voltage ( $V_{BE} = 0$ )	VCES	max.	45	60	80	V
Emitter-base voltage (open collector)	$V_{EBO}$	max.		5.0		V
Collector and emitter current	$I_C, I_E$	max.		8.0		Α

## BD533, BD535, BD537 BD534, BD536, BD538

Base current	IB	max.		1.0		A
Total power dissipation up to $T_C = 25^{\circ}C$		max.		50		W
Junction temperature	$T_j$	max.		150		$^{\circ}C$
Storage temperature	T <sub>stg</sub>		-65 to +150		$^{\circ}C$	
	- 318					
THERMAL RESISTANCE						
From junction to case	R <sub>thj-c</sub>			2.5		C/W
From junction to ambient	R <sub>th j-a</sub>			70		C/W
CHARACTERISTICS						
$T_{amb} = 25^{\circ}C$ unless otherwise specified			533	535	537	
			<i>534</i>	<i>536</i>	<i>538</i>	
Collector cutoff current						
$I_E = 0; V_{CB} = 45 V$	I <sub>CBO</sub>	max.	100	-	-	$\mu A$
$I_E = 0; V_{CB} = 60 V$	I <sub>CBO</sub>	max.	-	100	-	μA
$I_E = 0; V_{CB} = 80 V$	I <sub>CBO</sub>	max.	-	-	100	μA
$V_{BE} = 0; V_{CE} = 45V$	ICES	max.	100	-	-	μA
$V_{BE} = 0; V_{CE} = 60V$	ICES	max.	-	100	-	μA
$V_{BE} = 0; V_{CE} = 80V$	ICES	max.	-	-	100	$\mu A$
Emitter cut-off current						•
$I_{C} = 0; V_{EB} = 5 V$	I <sub>EBO</sub>	max.		1.0		mA
Breakdown voltages						
$I_C = 100 \text{ mA}; I_B = 0$	$V_{CEO(sus)}^*$	min.	45	60	80	V
$I_C = 1 mA; I_E = 0$	VCBO	min.	45	60	100	V
$I_E = 1 \text{ mA}; I_C = 0$	VEBO	min.		5.0		V
Saturation voltages						
$I_C = 2.0 \ A; \ I_B = 0.2 \ A$	$V_{CEsat}^*$	max.		0.8		V
$I_C = 6.0 \ A; \ I_B = 0.6 \ A$	V <sub>CEsat</sub> *	typ.		0.8		V
Base-emitter on voltage						
$I_C = 2A; V_{CE} = 2V$	$V_{BE(on)}^*$	max.		1.5		V
D.C. current gain						
$I_{C} = 10 m A; V_{CE} = 5V$	$h_{FE}^*$	min.	20	20	15	
$I_{C} = 500 mA; V_{CE} = 2V$	$h_{FE}^*$	min.		40		
			05		1.5	
$I_C = 2A; V_{CE} = 2V$	$h_{FE}^*$	min.	25	25	15	
Transition frequency	C			0.0		
$I_C = 500 \text{ mA}; V_{CE} = 1V$	$f_T$	min.		3.0		MHz
hFE Groups:						
$I_C = 2A; V_{CE} = 2V$	J	min.		30		
		max.		75		
$I_C = 3A; V_{CE} = 2V$		min.		15		
$I_C = 2A; V_{CE} = 2V$	K	min.		40		
$L = \mathcal{M}$		max.		100		
$I_C = 3A; V_{CE} = 2V$		min.		20		

\* Pulsed: pulse duration = 300  $\mu$ s; duty cycle = 1.5%.

Notes

## Disclaimer

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**Data Sheet**